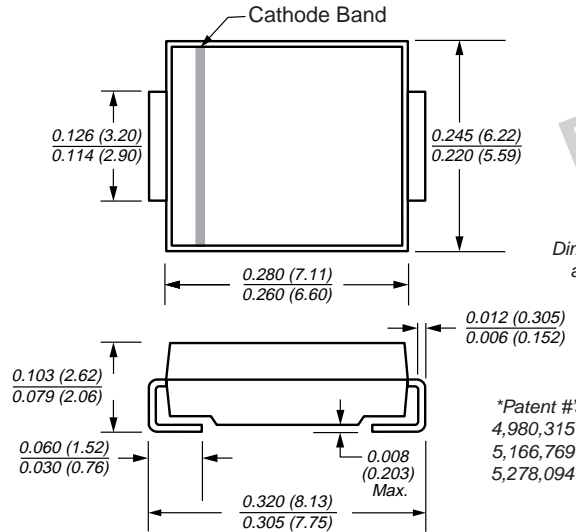




Automotive Surface Mount Transient Voltage Suppressors

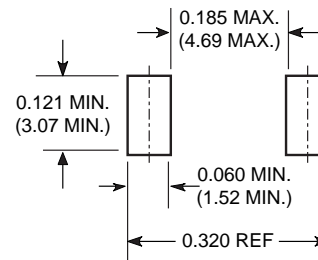
DO-214AB (SMC)

Breakdown Voltage 6.8 to 43V
Peak Pulse Power 1500W



Patented*

Mounting Pad Layout



Features

- Designed for under the hood surface mount applications
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Easy pick and place
- Low profile package
- Built-in strain relief
- Ideal for automated placement
- Exclusive patented PAR[®] oxide passivated chip construction
- 1500W peak pulse power capability with a 10/1000ms waveform, repetition rate (duty cycle): 0.01%
- Excellent clamping capability
- Low incremental surge resistance
- Very fast response time
- For devices with $V_{(BR)} \geq 10V$ I_D are typically less than 1.0mA at $T_A = 150^\circ C$
- High temperature soldering: 250°C/10 seconds at terminals

Available in uni-directional only

Mechanical Data

Case: JEDEC DO-214AB molded plastic body over passivated junction

Terminals: Solder plated, solderable per MIL-STD-750, Method 2026

Polarity: The color band denotes the cathode, which is positive with respect to the anode under normal TVS operation

Mounting Position: Any

Weight: 0.007 oz., 0.2 g

Packaging codes/options:

- 9/3.5K per 13" Reel (16mm tape), 30K/box
- 7/850 EA per 7" Reel (16mm tape), 27K/box

Maximum Ratings and Thermal Characteristics ($T_A = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Peak pulse power dissipation with a 10/1000 μs waveform ⁽¹⁾⁽²⁾ (Fig. 3)	P _{PPM}	Minimum 1500	W
Peak power pulse current with a 10/1000 μs waveform ⁽¹⁾ (Fig. 1)	I _{PPM}	See Next Table	A
Peak forward surge current 8.3ms single half sine-wave ⁽²⁾⁽³⁾	I _{FSM}	200	A
Maximum instantaneous forward voltage at 100A ⁽³⁾	V _F	3.5	V
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +185	°C

Notes: (1) Non-repetitive current pulse, per Fig.3 and derated above $T_A = 25^\circ C$ per Fig. 2

(2) Mounted on 0.31 x 0.31" (8.0 x 8.0mm) copper pads to each terminal

(3) Measured on 8.3ms single half sine-wave, or equivalent square wave, duty cycle = 4 pulses per minute maximum

TPSMC6.8 thru TPSMC43A

Vishay Semiconductors
formerly General Semiconductor



Electrical Characteristics (T_A = 25°C unless otherwise noted)

Device	Device Marking Code	Breakdown Voltage V _(BR) ⁽¹⁾ at I _T (V)		Test Current I _T (mA)	Stand-off Voltage V _{WM} (V)	Maximum Reverse Leakage at V _{WM} I _R (μA)	T _J = 150°C Maximum Reverse Leakage at V _{WM} I _D (μA)	Maximum Peak Pulse Surge Current I _{PPM} ⁽²⁾ (A)	Maximum Clamping Voltage at I _{PPM} V _c (V)
		Min.	Max.						
TPSMC6.8	DDP	6.12	7.48	10.0	5.50	1000	10000	139.0	10.8
TPSMC6.8A	DEP	6.45	7.14	10.0	5.80	1000	10000	143.0	10.5
TPSMC7.5	DFP	6.75	8.25	10.0	6.05	500	5000	128.0	11.7
TPSMC7.5A	DGP	7.13	7.88	10.0	6.40	500	5000	133.0	11.3
TPSMC8.2	DHP	7.38	9.02	10.0	6.63	200	2000	120.0	12.5
TPSMC8.2A	DKP	7.79	8.61	10.0	7.02	200	2000	124.0	12.1
TPSMC9.1	DLP	8.19	10.0	1.0	7.37	50	500	109.0	13.8
TPSMC9.1A	DMP	8.65	9.55	1.0	7.78	50	500	112.0	13.4
TPSMC10	DNP	9.00	11.0	1.0	8.10	20	200	100.0	15.0
TPSMC10A	DPP	9.50	10.5	1.0	8.55	20	200	103.0	14.5
TPSMC11	DQP	9.90	12.1	1.0	8.92	5.0	50	92.6	16.2
TPSMC11A	DRP	10.5	11.6	1.0	9.40	5.0	50	96.2	15.6
TPSMC12	DSP	10.8	13.2	1.0	9.72	2.0	10	86.7	17.3
TPSMC12A	DTP	11.4	12.6	1.0	10.2	2.0	10	89.8	16.7
TPSMC13	DUP	11.7	14.3	1.0	10.5	2.0	10	78.9	19.0
TPSMC13A	DVP	12.4	13.7	1.0	11.1	2.0	10	82.4	18.2
TPSMC15	DWP	13.5	16.5	1.0	12.1	1.0	10	68.2	22.0
TPSMC15A	DXP	14.3	15.8	1.0	12.8	1.0	10	70.8	21.2
TPSMC16	DYP	14.4	17.6	1.0	12.9	1.0	10	63.8	23.5
TPSMC16A	DZP	15.2	16.8	1.0	13.6	1.0	10	66.7	22.5
TPSMC18	EDP	16.2	19.8	1.0	14.5	1.0	10	56.6	26.5
TPSMC18A	EEP	17.1	18.9	1.0	15.3	1.0	10	59.5	25.2
TPSMC20	EFP	18.0	22.0	1.0	16.2	1.0	10	51.5	29.1
TPSMC20A	EGP	19.0	21.0	1.0	17.1	1.0	10	54.2	27.7
TPSMC22	EHP	19.8	24.2	1.0	17.8	1.0	10	47.0	31.9
TPSMC22A	EKP	20.9	23.1	1.0	18.8	1.0	10	49.0	30.6
TPSMC24	ELP	21.6	26.4	1.0	19.4	1.0	10	43.2	34.7
TPSMC24A	EMP	22.8	25.2	1.0	20.5	1.0	10	45.2	33.2
TPSMC27	ENP	24.3	29.7	1.0	21.8	1.0	10	38.4	39.1
TPSMC27A	EPP	25.7	28.4	1.0	23.1	1.0	10	40.0	37.5
TPSMC30	EQP	27.0	33.0	1.0	24.3	1.0	10	34.5	43.5
TPSMC30A	ERP	28.5	31.5	1.0	25.6	1.0	10	36.2	41.4
TPSMC33	ESP	29.7	36.3	1.0	26.8	1.0	10	31.4	47.7
TPSMC33A	ETP	31.4	34.7	1.0	28.2	1.0	10	32.8	45.7
TPSMC36	EUP	32.4	39.6	1.0	29.1	1.0	10	28.8	52.0
TPSMC36A	EVP	34.2	37.8	1.0	30.8	1.0	10	30.1	49.9
TPSMC39	EWP	35.1	42.9	1.0	31.6	1.0	10	26.6	56.4
TPSMC39A	EXP	37.1	41.0	1.0	33.3	1.0	10	27.8	53.9
TPSMC43	EYP	38.7	47.3	1.0	34.8	1.0	10	24.2	61.9
TPSMC43A	EZP	40.9	45.2	1.0	36.8	1.0	10	25.3	59.3

Notes:

- (1) V_(BR) measured after I_T applied for 300μs, I_T = square wave pulse or equivalent
- (2) Surge current waveform per Fig. 3 and derate per Fig. 2
- (3) All terms and symbols are consistent with ANSI/IEEE C62.35

Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig. 1 – Peak Pulse Power Rating Curve

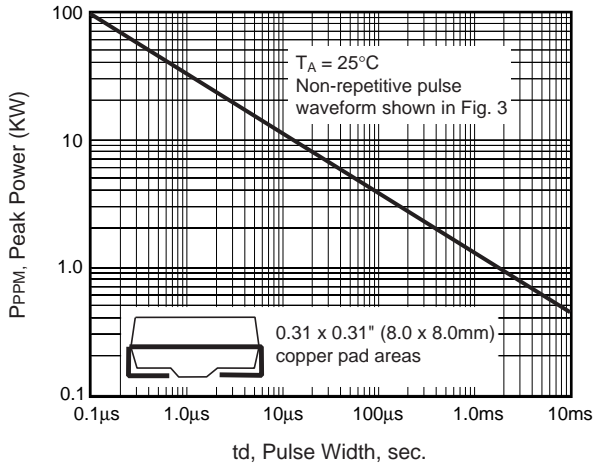


Fig. 2 – Pulse Derating Curve

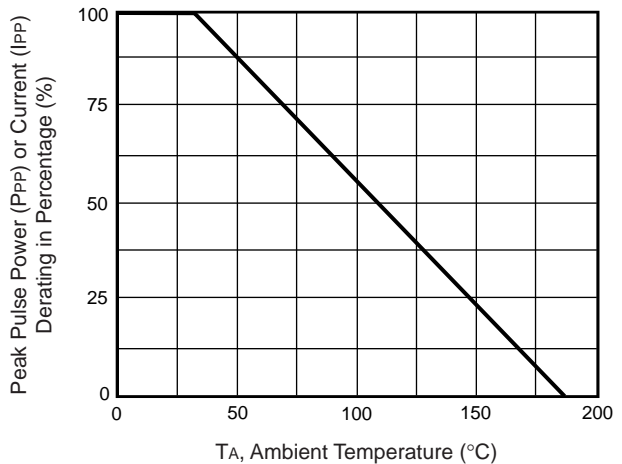


Fig. 3 – Pulse Waveform

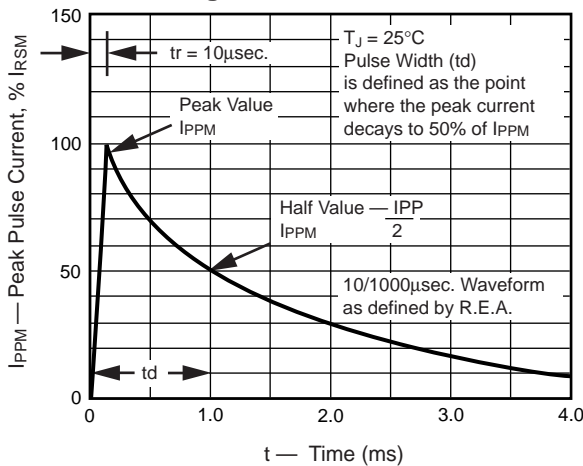


Fig. 4 – Typical Junction Capacitance

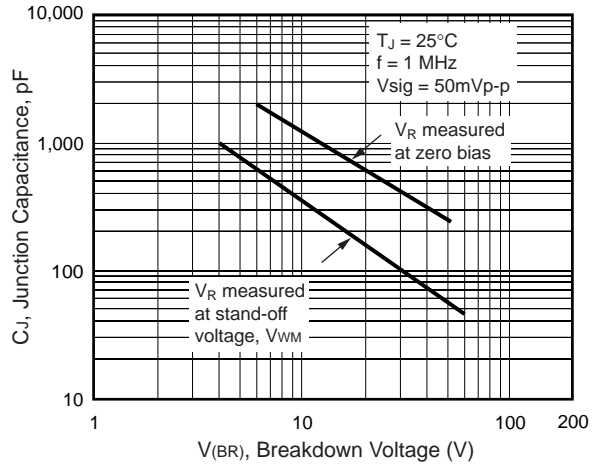


Fig. 5 – Maximum Non-Repetitive Peak Forward Surge Current

